TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT540P,TC74ACT540F,TC74ACT540FT TC74ACT541P,TC74ACT541F,TC74ACT541FT

Octal Bus Buffer

TC74ACT540P/F/FT Inverting, 3-State

Outputs

TC74ACT541P/F/FT Non-Inverting,

3-State Outputs

The TC74ACT540/TC74ACT541 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

These devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

The TC74ACT540 is an inverting type, and the TC74ACT541 is a non-inverting type.

When either G1 or G2 are high, the terminal outputs are in the high-impedance state.

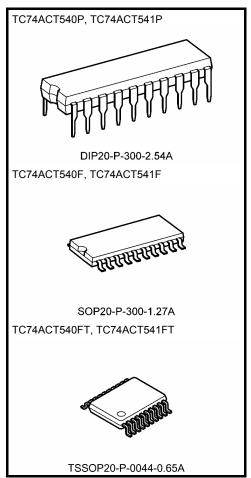
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 4.3 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu A$ (max) at $T_a = 25$ °C
- Compatible with TTL outputs
 - $V_{IL} = 0.8 V \text{ (max) } V_{IH} = 2.0 V \text{ (min)}$
- Symmetrical output impedance
 - $|I_{OH}| = I_{OL} = 24 \text{ mA (min)}$

Capability of driving 50Ω transmission lines.

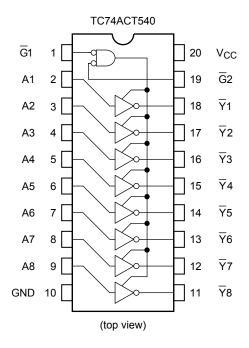
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F540/541

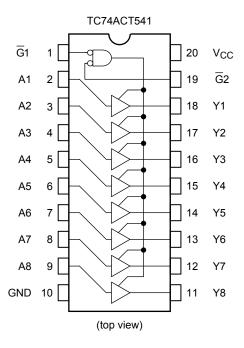


Weight

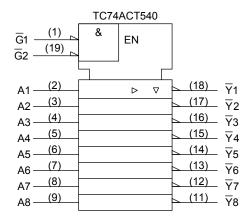
DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.)

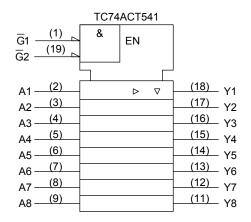
Pin Assignment





IEC Logic Symbol





Truth Table

	Inputs	Outputs			
G1	G2	An	Yn	\overline{Y}_n	
Н	Χ	Х	Z	Z	
Х	Н	Х	Z	Z	
L	L	Н	Н	L	
L	L	L	L	Н	

X: Don't care

Z: High impedance

Y_n: ACT541

Y_n: ACT540

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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	I _{CC}	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics S	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
	Cymbol			V _{CC} (V)	Min	Тур.	Max	Min	Max		
High-level input voltage	V _{IH}	_			4.5 to 5.5	2.0			2.0		٧
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	_	0.8	_	0.8	٧	
	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA		4.5	4.4	4.5	_	4.4	_	
High-level output voltage			I _{OH} = -24 mA		4.5	3.94	_	_	3.80	_	V
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	_	_	3.85	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA		4.5	_	0.0	0.1	_	0.1	
Low-level output voltage			I _{OL} = 24 mA		4.5	_	_	0.36	_	0.44	V
			I _{OL} = 75 mA	(Note)	5.5	_	_	_	_	1.65	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		5.5	_	_	±0.5	_	±5.0	μА	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND			5.5		_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND			5.5	_	_	8.0	_	80.0	μА
	Ic	Per input: $V_{IN} = 3.4 \text{ V}$ Other input: V_{CC} or GND			5.5	_	_	1.35	_	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.



AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	- ,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t _{pLH}		5.0 ± 0.5	_	5.0	8.3	1.0	9.5	ns
time (Note 2)	t_{pHL}	_							
Propagation delay	t_{pLH}		5.0 ± 0.5	_	5.0	8.3	1.0	9.5	ns
time (Note 3)	t_{pHL}	_							
Output enable time	t_{pZL}		5.0 ± 0.5	_	7.3	11.4	1.0	13.0	ns
	t _{pZH}	_							113
Output disable time	t_{pLZ}		5.0 ± 0.5	_	5.9	9.2	1.0	10.5	ns
	t _{pHZ}	_							113
Input capacitance	C_{IN}	_			5	10		10	pF
Output capacitance	C _{OUT}	_		_	10		_	_	pF
Power dissipation capacitance	C _{PD}	TC74ACT540		_	24	_	_	_	nΕ
	(Note 1)	TC74ACT541		_	27	_	_	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

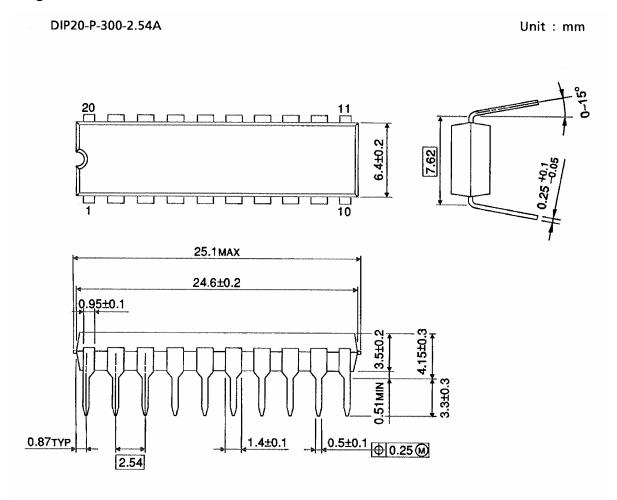
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Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

Note 2: For TC74ACT540 only Note 3: For TC74ACT541 only

Package Dimensions

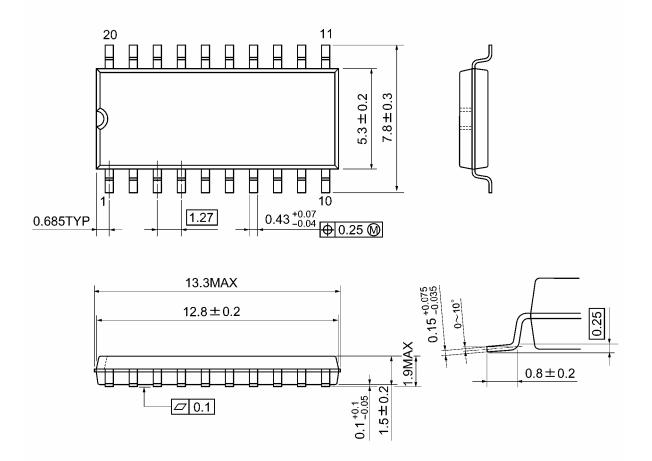


Weight: 1.30 g (typ.)



Package Dimensions

SOP20-P-300-1.27A Unit: mm

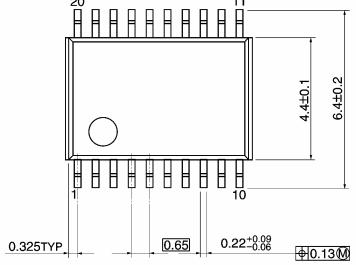


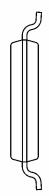
Weight: 0.22 g (typ.)

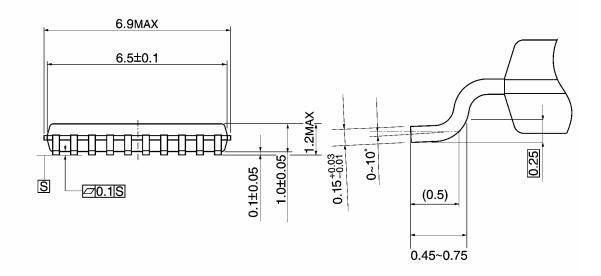


Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm







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Weight: 0.08 g (typ.)

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20070701-EN GENERAL

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